

Maximum Ratings

Parameter	Symbol	Value	Unit
Collector-emitter voltage	V_{CEO}	50	V
Collector-base voltage	V_{CBO}	50	
Input forward voltage	V _{i(fwd)}	30	
Input reverse voltage	V _{i(rev)}	5	
Collector current	I _C	100	mA
Total power dissipation-	P _{tot}		mW
BCR116, <i>T</i> _S ≤ 102°C		200	
BCR116S, <i>T</i> _S ≤ 115°C		250	
BCR116W, <i>T</i> _S ≤ 124°C		250	
Junction temperature	$T_{\rm j}$	150	°C
Storage temperature	T _{stg}	-65 150	

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point1)	R _{thJS}		K/W
BCR116		≤ 240	
BCR116S		≤ 140	
BCR116W		≤ 105	

 $^{^{1}}$ For calculation of R_{thJA} please refer to Application Note AN077 (Thermal Resistance Calculation)



Electrical Characteristics at $T_A = 25$ °C, unless otherwise specified **Symbol Values** Unit **Parameter** min. typ. max. **DC Characteristics** $V_{(BR)CEO}$ ٧ 50 Collector-emitter breakdown voltage $I_{\rm C}$ = 100 μ A, $I_{\rm B}$ = 0 Collector-base breakdown voltage $V_{(BR)CBO}$ 50 $I_{\rm C} = 10 \; \mu {\rm A}, \; I_{\rm E} = 0$ Collector-base cutoff current 100 nΑ I_{CBO} - $V_{\rm CB} = 40 \text{ V}, I_{\rm E} = 0$ 155 μΑ Emitter-base cutoff current *I*_{EBO} $V_{\rm EB} = 5 \text{ V}, I_{\rm C} = 0$ DC current gain¹⁾ 70 h_{FE} $I_{\rm C}$ = 5 mA, $V_{\rm CE}$ = 5 V Collector-emitter saturation voltage¹⁾ V_{CEsat} ٧ 0.3 $I_{\rm C}$ = 10 mA, $I_{\rm B}$ = 0.5 mA Input off voltage $V_{i(off)}$ 0.4 8.0 $I_{\rm C}$ = 100 μ A, $V_{\rm CE}$ = 5 V $V_{i(on)}$ Input on voltage 0.5 1.4 $I_{\rm C}$ = 2 mA, $V_{\rm CE}$ = 0.3 V R_1 3.2 Input resistor 4.7 6.2 $\mathsf{k}\Omega$ R_1/R_2 0.09 0.1 0.11 Resistor ratio **AC Characteristics** f_{T} MHz Transition frequency 150 $I_{\rm C}$ = 10 mA, $V_{\rm CE}$ = 5 V, f = 100 MHz рF Collector-base capacitance 3 C_{cb}

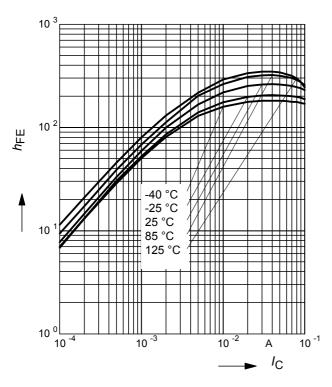
 $V_{CB} = 10 \text{ V}, f = 1 \text{ MHz}$

¹Pulse test: t < 300µs; D < 2%



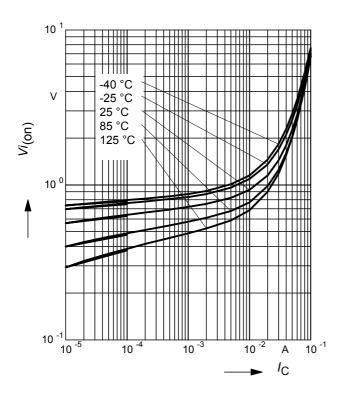
DC current gain $h_{FE} = f(I_C)$

 V_{CE} = 5V (common emitter configuration)



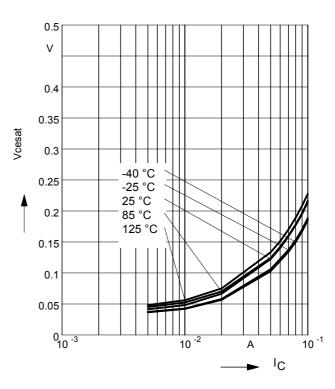
Input on Voltage $Vi_{(On)} = f(I_C)$

 V_{CE} = 0.3V (common emitter configuration)



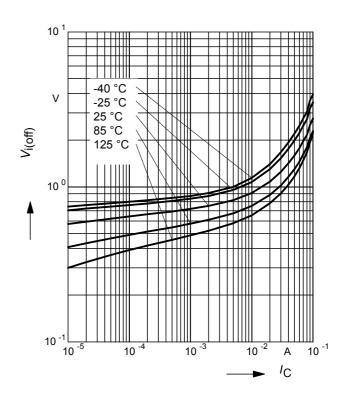
Collector-emitter saturation voltage

 $V_{CEsat} = f(I_{C}), I_{C}/I_{B} = 20$



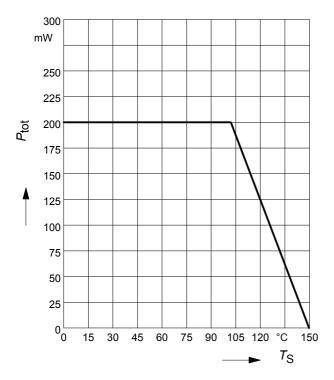
Input off voltage $V_{i(off)} = f(I_C)$

 V_{CE} = 5V (common emitter configuration)

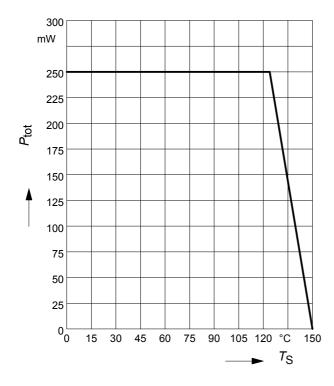




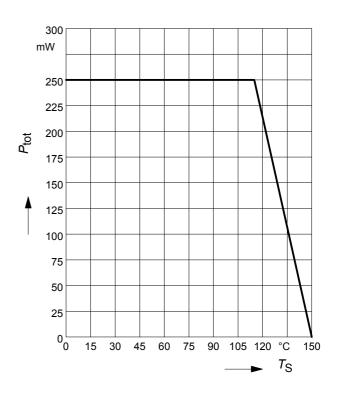
Total power dissipation $P_{tot} = f(T_S)$ BCR116



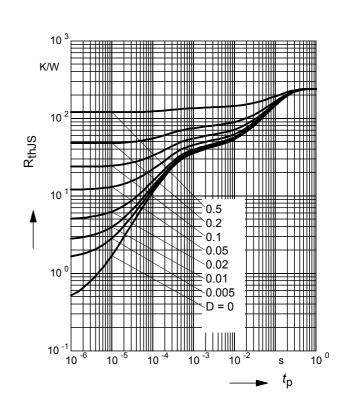
Total power dissipation $P_{tot} = f(T_S)$ BCR116W



Total power dissipation $P_{tot} = f(T_S)$ BCR116S



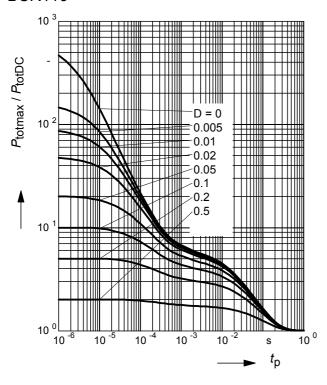
Permissible Pulse Load $R_{thJS} = f(t_p)$ BCR116





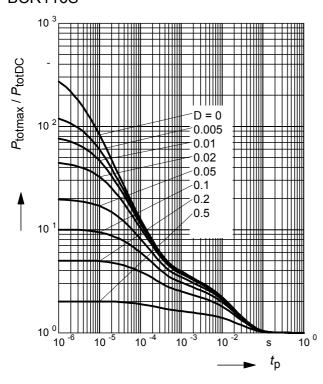
Permissible Pulse Load

 $P_{\text{totmax}}/P_{\text{totDC}} = f(t_{\text{p}})$ BCR116



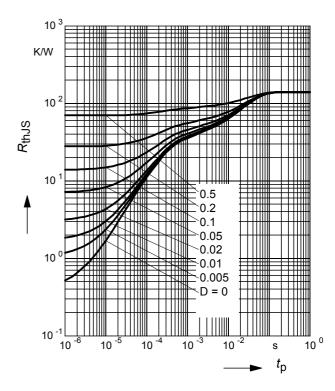
Permissible Pulse Load

 $P_{\text{totmax}}/P_{\text{totDC}} = f(t_{\text{p}})$ BCR116S



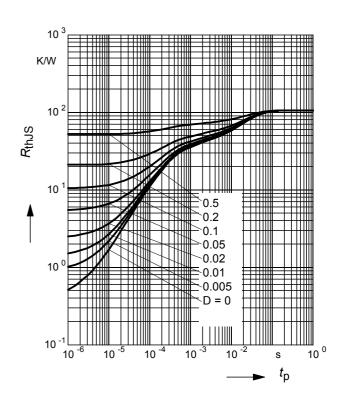
Permissible Puls Load $R_{thJS} = f(t_p)$

BCR116S



Permissible Puls Load R_{thJS} = $f(t_p)$

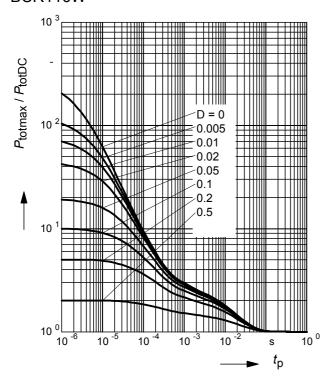
BCR116W





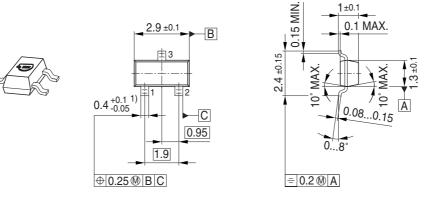
Permissible Pulse Load

 $P_{\text{totmax}}/P_{\text{totDC}} = f(t_{\text{p}})$ BCR116W



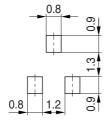


Package Outline

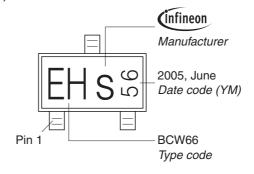


Foot Print



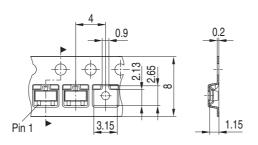


Marking Layout (Example)



Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel

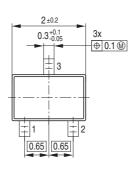


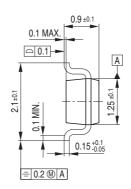
8



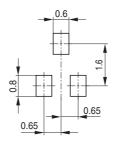
Package Outline



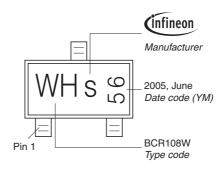




Foot Print

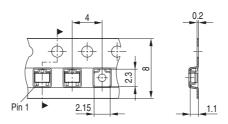


Marking Layout (Example)



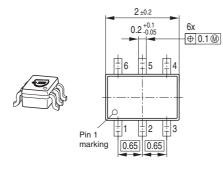
Standard Packing

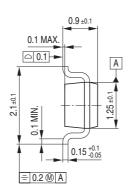
Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel



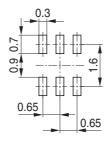


Package Outline



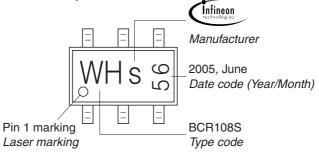


Foot Print



Marking Layout (Example)

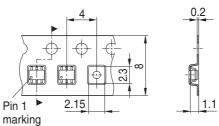
Small variations in positioning of Date code, Type code and Manufacture are possible.



Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel

For symmetric types no defined Pin 1 orientation in reel.





Edition 2009-11-16

Published by Infineon Technologies AG 81726 Munich, Germany

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